



A Product Line of **Diodes Incorporated** 

## LITE-ON SEMICONDUCTOR

# **LSC08065DW**

V

V

А

А

°C

SILICON CARBIDE SCHOTTKY DIODE		REVERSE VOLTAGE – 650 Volts FORWARD CURRENT – 8 Amperes	5
<ul> <li>FEATURES <ul> <li>Positive temperature coefficient for save operation and easy of paralleling</li> <li>175°C maximum operating junction temperature</li> <li>Extremely fast switching not dependent on temperature</li> <li>Qualified according to AEC-Q101 Rev_D</li> <li>Lead-Free Finish; RoHS Compliant (Notes 1 &amp; 2)</li> <li>Halogen and Antimony Free. "Green" Device (Note 3)</li> </ul> </li> <li>APPLICATION <ul> <li>Switch mode power supplies</li> <li>Power factor corrections</li> </ul> </li> <li>MECHANICAL DATA <ul> <li>Package Material: "Green" molding compound, UL flamm classification 94V-0, "Halogen-free".</li> <li>Moisture Sensitivity: Level 1 per J-STD-020</li> <li>Terminals: Matte Tin Finish Annealed over Copper Leadfi (Lead Free Plating). Solderable per MIL-STD-202, Method 208 (a)</li> <li>Weight: 0.989 grams (Approximate)</li> <li>Marking Code: LSC08065DW</li> </ul> </li> </ul>	ability	<b>DPAK</b> $ \int_{R} \frac{1}{R} \int_{R} $	
MAXIMUM RATINGS AND ELECTRICAL CHARACTER			
Ratings at 25°C ambient temperature unless otherwise s	pecilied.		
ABSOLUTE RATINGS PARAMETER	SYMBOL	VALUE	UNIT

ABSOLUTE KATINGS			
PARAMETER	SYMBOL	VALUE	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	650	
Maximum DC blocking voltage	V <sub>DC</sub>	650	
Maximum average rectified output current @Tc=120°C	I <sub>(AV)</sub>	8	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	48	
Operating junction and storage temperature range	T <sub>J,</sub> T <sub>STG</sub>	-55 ~ +175	

#### STATIC ELECTRICAL CHARACTERISTICS

STATIC ELECTRICAL CHAI	KACTERISTI	60				
PARAMETER	TEST CO	NDITIONS	SYMBOL	TYP	MAX	UNIT
Forward voltage (Note 4)	I <sub>F</sub> =8A	T <sub>J</sub> =25°C T <sub>J</sub> =175°C	V <sub>F</sub>	 2.19	1.70 2.25	V
Reverse leakage current	V <sub>R</sub> =650V	TJ=25°C TJ=175°C	I <sub>R</sub>	 10.26	230 700	μΑ

## **DYNAMIC ELECTRICAL CHARACTERISTICS**

Р	ARAMETER	SYMBOL	ТҮР	UNIT
Total Capacitive Charge	V <sub>R</sub> =400V,dI/dt=250A/µS, I <sub>F</sub> =8A	Q <sub>c</sub>	17	nC
Typical junction capacitance (	Note 5)	CJ	250	pF
	DICTICC			

#### THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	ТҮР	UNIT
Typical thermal resistance (Notes 6, 7)	RthJ <sub>c</sub>	3	°C ///
Typical merinal resistance (notes 6, 7)	RthJ∟	3	C/W

Notes:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

4. 300µs pulse width, 2% duty cycle.
 5. Measured at 1.0MHz and applied voltage of 1.0V DC.

6. Thermal resistance test performed in accordance with JESD-51.

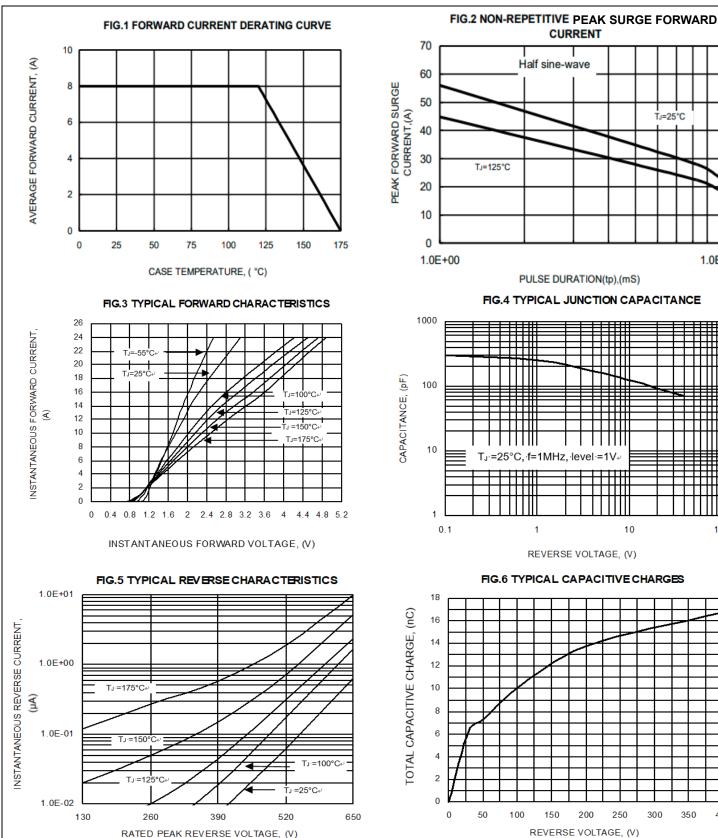
7. The unit mounted on copper plate Heatsink (100mm x 100mm x 1.9mm & 40mm x 40mm x 1.4mm).



1.0E+01

100

#### RATING AND CHARACTERISTIC CURVES LSC08065DW



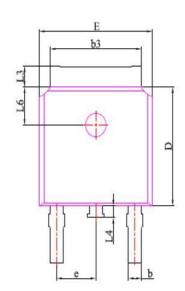
350

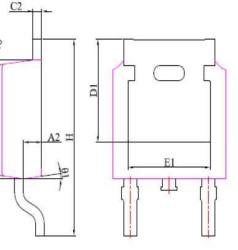
400

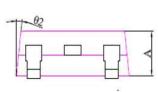


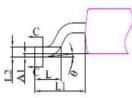
#### LITE-ON SEMICONDUCTOR

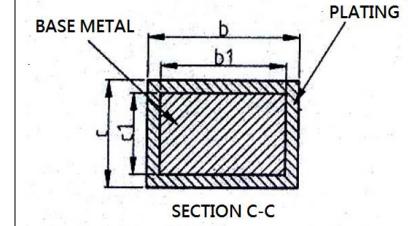
Package Dimension:











0

DIM	MIN	TYP	MAX
A	2.20	2.30	2.40
A1	0.00		0.15
A2	0.97	1.07	1.17
b	0.68	0.78	0.90
b1	0.66	0.76	0.88
b3	5.20	5.33	5.50
C	0.43	0.53	0.63
C1	0.41	0.51	0.61
C2	0.43	0.53	0.63
D	5.98	6.10	6.22
D1		5.30 REF	
E	6.40	6.60	6.80
E1	4.63	4.83	5.03
е		2.286 REF	
Н	9.40	10.10	10.50
L	1.38	1.50	1.75
L1		2.90 REF	
L2		0.51 BSC	
L3	0.88		1.28
L4	2 <b></b> 2		1.00
L6	1.65	1.80	1.95
Θ	0°		8°
<b>Θ</b> 1	5°	<b>7</b> °	9°
<b>O</b> 2	5°	<b>7</b> °	<b>9°</b>
All	dimensio	n in millim	eter

TO-252



## **Ordering Information:**

Part Number     Package     Qty.     Carrier       LSC08065DW     DPAK     2500pcs     Tape & Ree       Information:     Image: Construction of the second of	LSC08065DW DPAK 2500pcs	
ng Information:	LSC08065DW DPAK 2500pcs	Tape & Ree
Logo LT YMWW LSC08065DW Date Code Y = Year Code WW = Week Code WW = Week Code	ng Information:	
Logo LT YMWW LSC08065DW Y = Year Code M = Assembly Code WW = Week Code Product Type Marking Code		
	Logo	/ Code Code



#### LITE-ON SEMICONDUCTOR

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